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APPLICATION NO.	FI	LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/740,205	12/18/2003		Krishnaswamy Ramkumar	5298-08101 PM01039D	2236
35617	7590	06/29/2004		EXAMINER	
CONLEY I	•	C.	PHAM, HOAI V		
	P.O. BOX 684908 AUSTIN, TX 78768			ART UNIT	PAPER NUMBER
,				2814	- · · · · ·
				DATE MAILED: 06/29/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)					
	10/740,205	RAMKUMAR ET AL.					
Office Action Summary	Examiner	Art Unit					
	Hoai V Pham	· 2814					
The MAILING DATE of this communication app Period for Reply	ears on the cover she t with the c	orrespondence address					
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply 1 ff NO period for reply is specified above, the maximum statutory period w Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be timed within the statutory minimum of thirty (30) days will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. O (35 U.S.C. § 133).					
Status							
1) Responsive to communication(s) filed on 18 Dec	<u>ecember 2003</u> .						
2a) ☐ This action is <b>FINAL</b> . 2b) ☑ This	This action is <b>FINAL</b> . 2b)⊠ This action is non-final.						
,	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
4) ⊠ Claim(s) 17-20 is/are pending in the application 4a) Of the above claim(s) is/are withdray 5) □ Claim(s) is/are allowed. 6) ⊠ Claim(s) 17,18 and 20 is/are rejected. 7) ⊠ Claim(s) 19 is/are objected to. 8) □ Claim(s) are subject to restriction and/or	vn from consideration.						
Application Papers							
9) ☐ The specification is objected to by the Examine 10) ☑ The drawing(s) filed on 18 December 2003 is/a Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) ☐ The oath or declaration is objected to by the Ex	re: a)⊠ accepted or b)⊡ objector drawing(s) be held in abeyance. See ion is required if the drawing(s) is obj	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).					
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreign  a) All b) Some * c) None of:  1. Certified copies of the priority documents  2. Certified copies of the priority documents  3. Copies of the certified copies of the priority application from the International Bureau  * See the attached detailed Office action for a list	s have been received. s have been received in Application rity documents have been receive u (PCT Rule 17.2(a)).	on No ed in this National Stage					
Attachment(s)							
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 4) Interview Summary (PTO-413) Paper No(s)/Mail Date							
<ul> <li>2) Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)</li> <li>Paper No(s)/Mail Date 4/13/04.</li> </ul>		atent Application (PTO-152)					

# DETAILED ACTION

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### Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

2. Claims 17-18 and 20 rejected under 35 U.S.C. 102(e) as being anticipated by Kunikiyo [U.S. Pat. 6,661,065].

With respect to claim 17, Kunikiyo (fig. 21, cols. 22-23) discloses a silicon-oxide-nitride-oxide-silicon structure (see col. 22, lines 66-67 and col. 23, line 1) comprising a first oxide layer (111) arranged upon a silicon-based semiconductor substrate (1), wherein an interface between the silicon-based semiconductor substrate and the first oxide layer comprises deuterium (see col. 19, lines 13-16).

With respect to claim 18, Kunikiyo inherently discloses a lateral length of the interface between the silicon-based semiconductor substrate (1) and the first oxide layer (111) is bound by opposing sidewalls of the structure, and wherein said deuterium is arranged across an entirety of said lateral length.

With respect to claim 20, Kunikiyo discloses that the nitride layer (121) comprises deuterium (see col. 22, line 46).

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#### Allowable Subject Matter

3. Claim 19 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

4. The following is an examiner's statement of reasons for allowance: the prior of record fails to disclose the combination of a semiconductor device structure recited in the base claim 17, including the combination of the structure comprising: a nitride layer arranged upon and in contact with the first oxide layer; a second oxide layer arranged upon and in contact with the nitride layer, and a second silicon layer arranged upon and in contact with the second oxide layer, wherein an interface between the second silicon layer and second oxide layer comprises deuterium.

#### Conclusion

- 5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Hoai V Pham whose telephone number is 571-272-1715. The examiner can normally be reached on 9:30A.M. 8:00P.M..
- 6. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael M. Fahmy can be reached on 571-272-1705. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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7. Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Hoai Pham

Patent Examiner